

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	19	09/466934	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/04 09:48
S2	61918	SOI	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/29 20:11
S3	4425	S2 and (substrate with (insulat\$3 oxide box) with (semiconductor near (layer film)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 14:39
S4	633	S3 and recess\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/29 20:14
S5	542	S4 and (source drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/29 20:14
S6	448	S5 and isolat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/29 20:14
S7	453	S5 and (isolat\$3 STI LOCOS)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 12:28
S8	416	S7 and gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 12:29

S9	360	S8 and channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 12:28
S10	84	S9 and (recess\$2 with (source drain))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 12:27
S11	61918	SOI	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 12:27
S12	505	S11 and (recess\$2 with (source drain))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 14:40
S13	339	S12 and (isolat\$3 STI LOCOS)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 12:28
S14	286	S13 and channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 12:28
S15	275	S14 and gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 12:29
S16	23	("4788160"   "4851257"   "5089872"   "5168072"   "5242847"   "5314832"   "5336903"   "5338698"   "5453389"   "5571744"   "5618755"   "5665646"   "5686331"   "5702972"   "5707721"   "5710450"   "5716861"   "5763932"   "5793089"   "5851891"   "6087706"   "6124189"   "6165826").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/30 13:13

S17	17	("4788160"   "4851257"   "5168072"   "5314832"   "5338698"   "5618755"   "5665646"   "5686331"   "5707721"   "5710450"   "5736435"   "5739573"   "5759886"   "5783486"   "5795808"   "5889331"   "RE35111").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/30 13:20
S18	4	("4485550"   "4873204"   "4905073"   "5053848").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/30 13:22
S19	1952	SOI with (substrate with (insulat\$3 oxide box) with (semiconductor near (layer film)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 14:40
S20	43	S19 and (recess\$2 with (source drain))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/04/30 14:41
S21	0	gate near2 angle near2 (side near surface near recess\$2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/03 19:00
S22	3	gate with angle with (side near surface near recess\$2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/03 19:04
S23	2	(semiconductor near (layer film)) with angle with (side near surface near recess\$2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/03 19:13
S24	135	angle with (side near surface near recess\$2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/03 19:14
S25	6	S24 and SOI	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/03 19:14

S26	2	("6314021").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/05/04 09:48
-----	---	-----------------	--------------------------------------------------------------------	----	-----	------------------